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# Onsemi

# Small Signal MOSFET

60 V, 380 mA, Single, N-Channel, SOT-23

# 2N7002K, 2V7002K

#### Features

- ESD Protected
- Low R<sub>DS(on)</sub>
- Surface Mount Package
- 2V Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### Applications

- Low Side Load Switch
- Level Shift Circuits
- DC–DC Converter
- Portable Applications i.e. DSC, PDA, Cell Phone, etc.

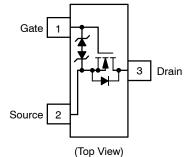
#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise stated)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	60	V
Gate-to-Source Voltage	V <sub>GS</sub>	±20	V
$ \begin{array}{ll} \text{Drain Current (Note 1)} \\ \text{Steady State 1 sq in Pad} & T_{\text{A}} = 25^{\circ}\text{C} \\ T_{\text{A}} = 85^{\circ}\text{C} \end{array} $	Ι <sub>D</sub>	380 270	mA
$ \begin{array}{l} \mbox{Drain Current (Note 2)} \\ \mbox{Steady State Minimum Pad} & T_A = 25^{\circ}C \\ \mbox{T}_A = 85^{\circ}C \end{array} $	Ι <sub>D</sub>	320 230	mA
Power Dissipation Steady State 1 sq in Pad Steady State Minimum Pad	P <sub>D</sub>	420 300	mW
Pulsed Drain Current ( $t_p = 10 \ \mu s$ )	I <sub>DM</sub>	5.0	А
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	–55 to +150	°C
Source Current (Body Diode)	۱ <sub>S</sub>	300	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)	ΤL	260	°C
Gate-Source ESD Rating (HBM, Method 3015)	ESD	2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

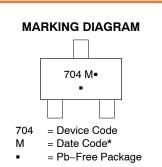
V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> MAX	I <sub>D</sub> MAX
60 V	1.6 Ω @ 10 V	380 mA
60 V	2.5 Ω @ 4.5 V	360 IIIA

### SIMPLIFIED SCHEMATIC









(NOTE: Microdot may be in either location)

\*Date Code orientation and/or location may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
2N7002KT1G, 2V7002KT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
2N7002KT7G	SOT-23 (Pb-Free)	3500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Surface-mounted on FR4 board using 1 sq in pad size with 1 oz Cu.
Surface-mounted on FR4 board using 0.08 sq in pad size with 1 oz Cu.

#### **THERMAL CHARACTERISTICS**

Characteristic	Symbol	Мах	Unit
Junction-to-Ambient - Steady State (Note 3)	$R_{ hetaJA}$	300	°C/W
Junction-to-Ambient – t $\leq$ 5 s (Note 3)	1	92	
Junction-to-Ambient - Steady State (Note 4)		417	
Junction-to-Ambient – t $\leq$ 5 s (Note 4)		154	

Surface-mounted on FR4 board using 1 sq in pad size with 1 oz Cu.
Surface-mounted on FR4 board using 0.08 sq in pad size with 1 oz Cu.

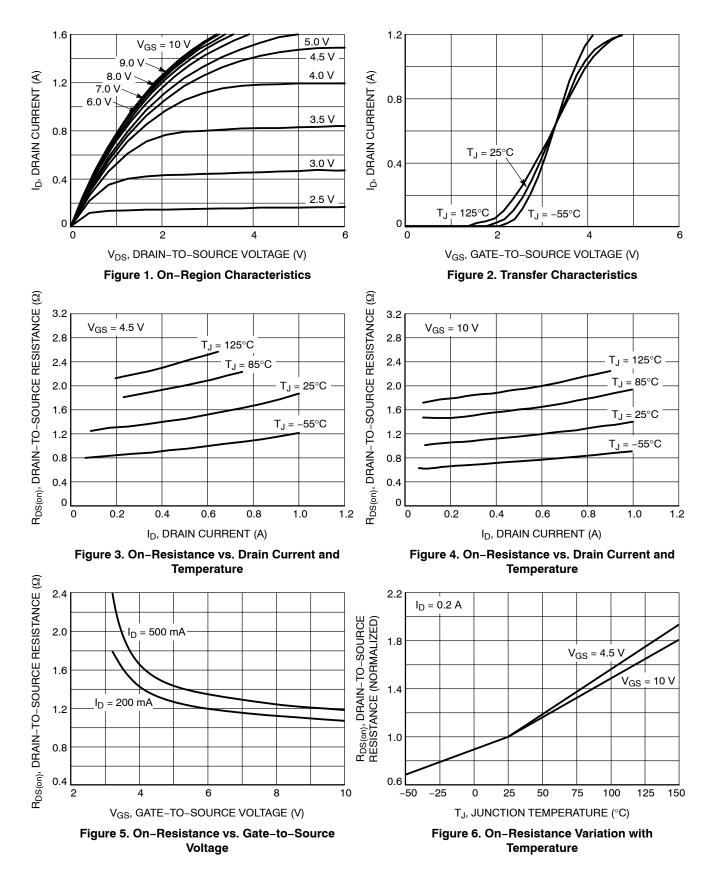
#### ELECTRICAL CHARACTERISTICS (T,I = 25°C unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0 V,	I <sub>D</sub> = 250 μA	60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>				71		mV/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V,	$T_J = 25^{\circ}C$			1	μA
		V <sub>DS</sub> = 60 V	T <sub>J</sub> = 125°C			10	
		V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 50 V	T <sub>J</sub> = 25°C			100	nA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	I <sub>GSS</sub> V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±20 V				±10	μΑ
		V <sub>DS</sub> = 0 V, V	V <sub>GS</sub> = ±10 V			450	nA
		V <sub>DS</sub> = 0 V, V	/ <sub>GS</sub> = ±5.0 V			150	nA
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}$	, I <sub>D</sub> = 250 μA	1.0		2.3	V
Negative Threshold Temperature Coefficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				4.0		mV/°C
Drain-to-Source On Resistance	I-to-Source On Resistance $R_{DS(on)}$ $V_{GS}$ = 10 V, $I_D$ = 500 mA		I <sub>D</sub> = 500 mA		1.19	1.6	Ω
		V <sub>GS</sub> = 4.5 V	, I <sub>D</sub> = 200 mA		1.33	2.5	
Forward Transconductance	<b>9</b> FS	V <sub>DS</sub> = 5 V,	I <sub>D</sub> = 200 mA		530		mS
CHARGES AND CAPACITANCES		-					-
Input Capacitance	C <sub>ISS</sub>				24.5	45	pF
Output Capacitance	C <sub>OSS</sub>	0.0	, f = 1 MHz, = 20 V		4.2	8.0	
Reverse Transfer Capacitance	C <sub>RSS</sub>	VDS 1	- 20 V		2.2	5.0	
Total Gate Charge	Q <sub>G(TOT)</sub>	V <sub>GS</sub> = 4.5 V, V <sub>DS</sub> = 10 V; I <sub>D</sub> = 200 mA			0.7		nC
Threshold Gate Charge	Q <sub>G(TH)</sub>				0.1		
Gate-to-Source Charge	Q <sub>GS</sub>				0.3		
Gate-to-Drain Charge	Q <sub>GD</sub>				0.1		
SWITCHING CHARACTERISTICS, $V_{GS}$	= V (Note 6)						
Turn-On Delay Time	t <sub>d(ON)</sub>	$V_{GS}$ = 10 V, $V_{DD}$ = 25 V, I <sub>D</sub> = 500 mA, R <sub>G</sub> = 25 Ω			12.2		ns
Rise Time	t <sub>r</sub>				9.0		]
Turn-Off Delay Time	t <sub>d(OFF)</sub>				55.8		]
Fall Time	t <sub>f</sub>	]			29		
DRAIN-SOURCE DIODE CHARACTER	ISTICS						
Forward Diode Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0 V,	$T_J = 25^{\circ}C$		0.8	1.2	V
		I <sub>S</sub> = 200 mA	T <sub>J</sub> = 85°C		0.7		]

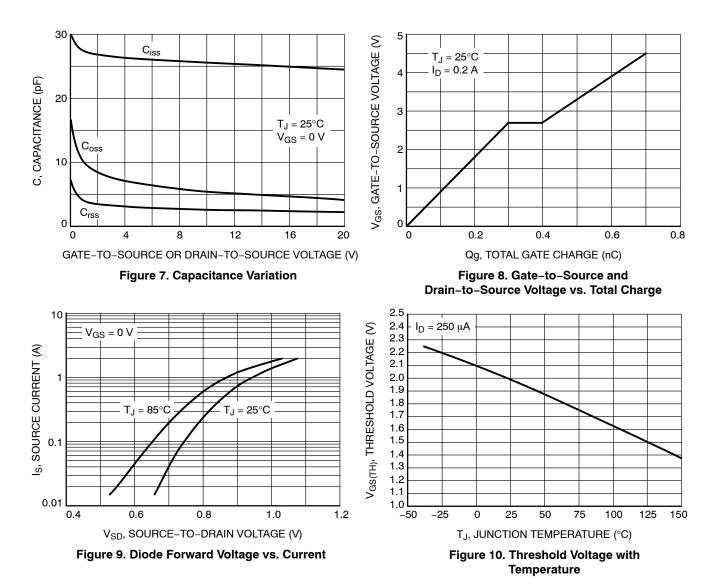
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulse Test: pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%

6. Switching characteristics are independent of operating junction temperatures

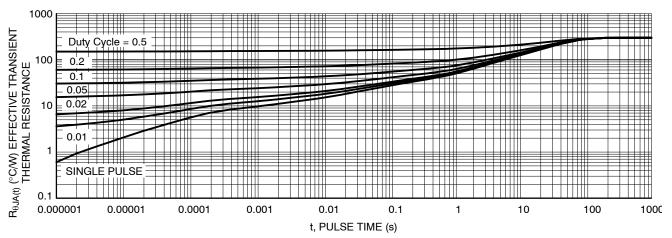
#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**





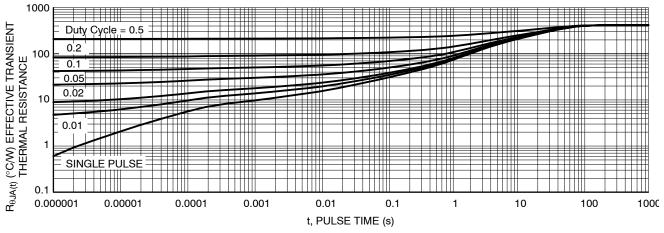


Figure 12. Thermal Response – minimum pad

# semi



#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

**ISSUE AU** 

DATE 14 AUG 2024













XXX = Specific Device Code М = Date Code

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS					
DIM	MIN	NOM	МАХ		
А	0.89	1.00	1.11		
A1	0.01	0.06	0.10		
b	0.37	0.44	0.50		
с	0.08	0.14	0.20		
D	2.80	2.90	3.04		
E	1.20	1.30	1.40		
е	1.78	1.90	2.04		
L	0.30	0.43	0.55		
L1	0.35	0.54	0.69		
Ηe	2.10	2.40	2.64		
Т	0°		10°		

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

#### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **STYLES ON PAGE 2**

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#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CÁSE 318** ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	I	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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